



Features

- Surface Mount SMA package
- Standoff Voltage: 12 to 58 volts
- Power Dissipation: 400 watts
- RoHS compliant*
- AEC-Q101 compliant**

Applications

- Protection of power buses
- Protection of I/O interfaces
- Overvoltage transient protection
- Automotive
 - Entertainment applications
 - Comfort applications
- Telecom, computer, industrial and consumer electronics applications

SMAJ-Q Transient Voltage Suppressor Diode Series

General Information

Bourns offers Transient Voltage Suppressor Diodes for surge and ESD protection applications, in compact chip package DO-214AC (SMA) size format. The Transient Voltage Suppressor series offers a choice of Working Peak Reverse Voltage from 12 V up to 58 V. Typical fast response times are less than 1.0 picosecond from 0 V to Breakdown Voltage.

Bourns® Chip Diodes conform to JEDEC standards, are easy to handle with standard pick and place equipment and the flat configuration minimizes roll away.

Electrical Characteristics (@ T_A = 25 °C Unless Otherwise Noted)

Parameter	Symbol	Value	Unit
Minimum Peak Pulse Power Dissipation (T _P = 1 ms) (Note 1,2)	P _{PK}	400	Watts
Peak Forward Surge Current 8.3 ms Single Half Sine Wave Superimposed on Rated Load (JEDEC Method) (Note 3)	I _{FSM}	40	Amps
Operating Temperature Range	T _J	-55 to +150	°C
Storage Temperature Range	T _{STG}	-55 to +150	°C

1. Non-repetitive current pulse, per Pulse Waveform graph and derated above T_A = 25 °C per Pulse Derating Curve.
2. Mounted on 5.0 mm² (0.03 mm thick) copper pads to each terminal.
3. 8.3 ms Single Half-Sine Wave duty cycle = 4 pulses maximum per minute (unidirectional units only).

BOURNS®

Asia-Pacific: Tel: +886-2 2562-4117 • Email: asiacus@bourns.com

EMEA: Tel: +36 88 520 390 • Email: eurocus@bourns.com

The Americas: Tel: +1-951 781-5500 • Email: americus@bourns.com

www.bourns.com

*RoHS Directive 2002/95/EC Jan. 27, 2003 including annex and RoHS Recast 2011/65/EU June 8, 2011.

**"Q" part number suffix indicates AEC-Q101 compliance.

Specifications are subject to change without notice.

The device characteristics and parameters in this data sheet can and do vary in different applications and actual device performance may vary over time. Users should verify actual device performance in their specific applications.

SMAJ-Q Transient Voltage Suppressor Diode Series

BOURNS®

Electrical Characteristics (@ T_A = 25 °C Unless Otherwise Noted)

Unidirectional Device		Bidirectional Device		Breakdown Voltage V _{BR} (Volts)			Working Peak Reverse Voltage	Maximum Reverse Leakage @ V _{RWM}	Maximum Reverse Voltage @ I _{RSM}	Maximum Reverse Surge Current
Part No.	Marking	Part No.	Marking	Min.	Max.	@ I _T (mA)	V _{RWM} (V)	I _R (μA)	V _{RSM} (V)	I _{RSM} (A)
SMAJ12A-Q	IEQ	SMAJ12CA-Q	UEQ	13.3	14.7	1.0	12	1.0	19.9	20.1
SMAJ13A-Q	IGQ	SMAJ13CA-Q	UGQ	14.4	15.9	1.0	13	1.0	21.5	18.6
SMAJ14A-Q	IKQ	SMAJ14CA-Q	UKQ	15.6	17.2	1.0	14	1.0	23.2	17.2
SMAJ15A-Q	IMQ	SMAJ15CA-Q	UMQ	16.7	18.5	1.0	15	1.0	24.4	16.4
SMAJ16A-Q	IPQ	SMAJ16CA-Q	UPQ	17.8	19.7	1.0	16	1.0	26.0	15.3
SMAJ17A-Q	IRQ	SMAJ17CA-Q	URQ	18.9	20.9	1.0	17	1.0	27.6	14.5
SMAJ18A-Q	ITQ	SMAJ18CA-Q	UTQ	20.0	22.1	1.0	18	1.0	29.2	13.7
SMAJ20A-Q	IVQ	SMAJ20CA-Q	UVQ	22.2	24.5	1.0	20	1.0	32.4	12.3
SMAJ22A-Q	IXQ	SMAJ22CA-Q	UXQ	24.4	26.9	1.0	22	1.0	35.5	11.3
SMAJ24A-Q	IZQ	SMAJ24CA-Q	UZQ	26.7	29.5	1.0	24	1.0	38.9	10.3
SMAJ26A-Q	JEQ	SMAJ26CA-Q	VEQ	28.9	31.9	1.0	26	1.0	42.1	9.5
SMAJ28A-Q	JGQ	SMAJ28CA-Q	VGQ	31.1	34.4	1.0	28	1.0	45.4	8.8
SMAJ30A-Q	JKQ	SMAJ30CA-Q	VKQ	33.3	36.8	1.0	30	1.0	48.4	8.3
SMAJ33A-Q	JMQ	SMAJ33CA-Q	VMQ	36.7	40.6	1.0	33	1.0	53.3	7.5
SMAJ36A-Q	JPQ	SMAJ36CA-Q	VPQ	40.0	44.2	1.0	36	1.0	58.1	6.9
SMAJ40A-Q	JRQ	SMAJ40CA-Q	VRQ	44.4	49.1	1.0	40	1.0	64.5	6.2
SMAJ43A-Q	JTQ	SMAJ43CA-Q	VTQ	47.8	52.8	1.0	43	1.0	69.4	5.8
SMAJ45A-Q	JVQ	SMAJ45CA-Q	VVQ	50.0	55.3	1.0	45	1.0	72.7	5.5
SMAJ48A-Q	JXQ	SMAJ48CA-Q	VXQ	53.3	58.9	1.0	48	1.0	77.4	5.2
SMAJ51A-Q	JZQ	SMAJ51CA-Q	VZQ	56.7	62.7	1.0	51	1.0	82.4	4.9
SMAJ54A-Q	REQ	SMAJ54CA-Q	WEQ	60.0	66.3	1.0	54	1.0	87.1	4.6
SMAJ58A-Q	RGQ	SMAJ58CA-Q	WGQ	64.4	71.2	1.0	58	1.0	93.6	4.3

- Notes: 1. Suffix 'A' denotes a 5 % tolerance unidirectional device.
 2. Suffix 'CA' denotes a 5 % tolerance bidirectional device.

Specifications are subject to change without notice.

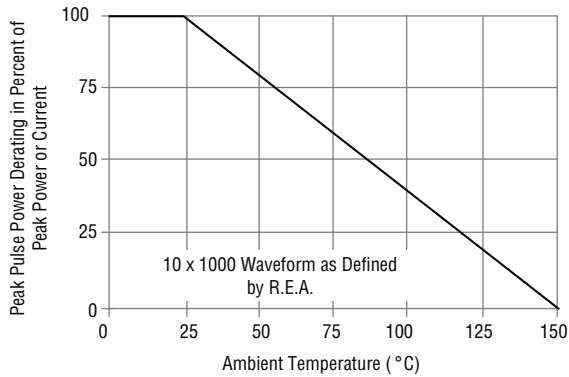
The device characteristics and parameters in this data sheet can and do vary in different applications and actual device performance may vary over time. Users should verify actual device performance in their specific applications.

SMAJ-Q Transient Voltage Suppressor Diode Series

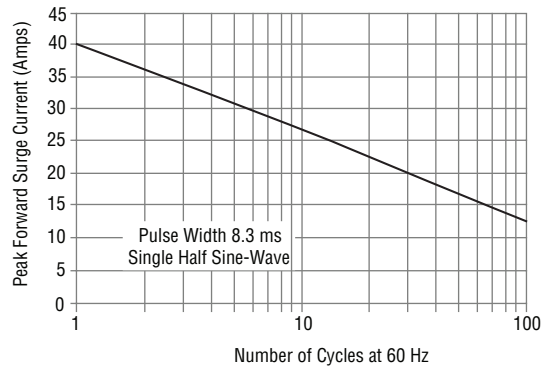


Performance Graphs

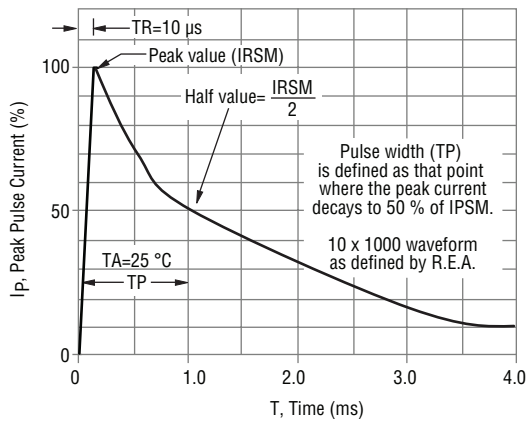
Peak Pulse Power Derating Curve



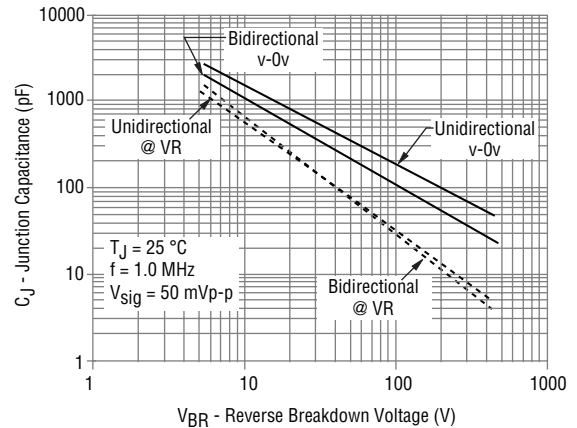
Maximum Non-Repetitive Surge Current



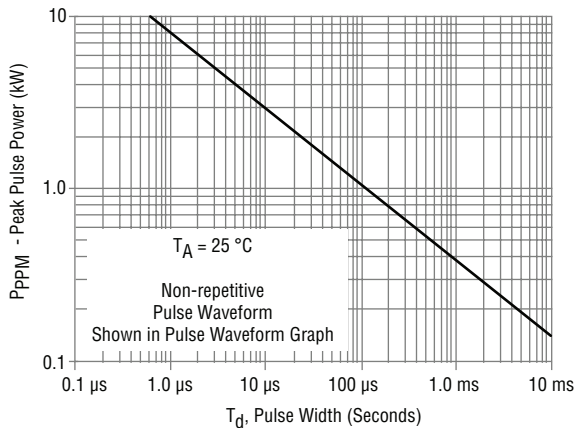
Pulse Waveform



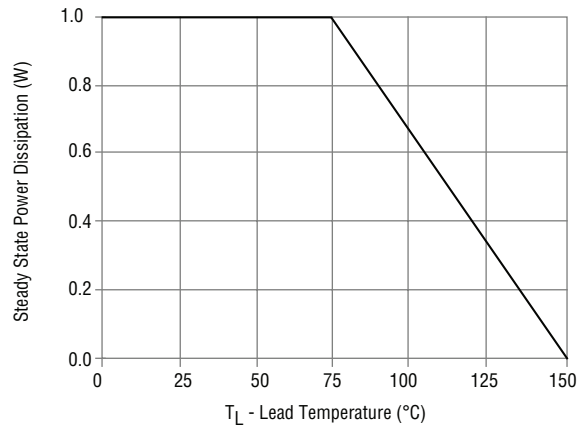
Typical Junction Capacitance



Pulse Rating Curve



Steady State Power Derating Curve

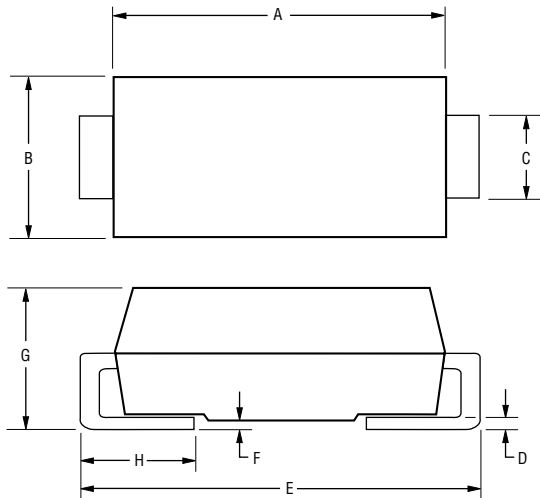


Specifications are subject to change without notice. The device characteristics and parameters in this data sheet can and do vary in different applications and actual device performance may vary over time. Users should verify actual device performance in their specific applications.

SMAJ-Q Transient Voltage Suppressor Diode Series



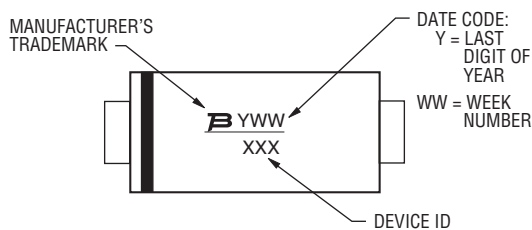
Product Dimensions



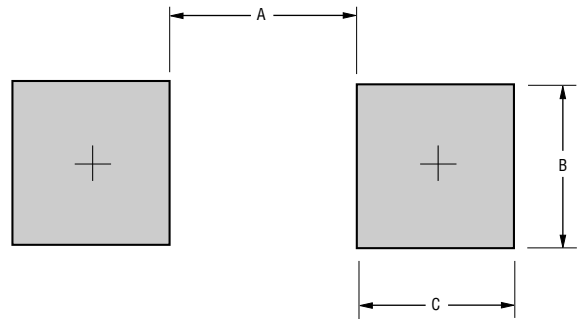
Dimension	SMA (DO-214AC)
A	$\frac{3.99 - 4.50}{(0.157 - 0.157)}$
B	$\frac{2.54 - 2.79}{(0.100 - 0.110)}$
C	$\frac{1.25 - 1.65}{(0.049 - 0.065)}$
D	$\frac{0.15 - 0.31}{(0.006 - 0.112)}$
E	$\frac{4.93 - 5.28}{(0.194 - 0.208)}$
F	$\frac{0.203}{(0.008)}$ MAX.
G	$\frac{1.98 - 2.29}{(0.078 - 0.090)}$
H	$\frac{0.76 - 1.52}{(0.030 - 0.060)}$

DIMENSIONS: $\frac{\text{MM}}{\text{(INCHES)}}$

Typical Part Marking



Recommended Footprint



Dimension	SMA (DO-214AC)
A (Max.)	$\frac{2.70}{(0.106)}$
B (Min.)	$\frac{2.10}{(0.083)}$
C (Min.)	$\frac{1.27}{(0.050)}$

DIMENSIONS: $\frac{\text{MM}}{\text{(INCHES)}}$

Physical Specifications

Case Molded plastic per UL Class 94V-0
 Polarity..... Cathode band indicates unidirectional device
 No cathode band indicates bidirectional device

How to Order

Package SMAJ 12 CA - Q
 SMAJ = SMA/DO-214AC
 Working Peak Reverse Voltage 12 = 12 V_{RWM} (Volts)
 Suffix
 A = 5 % Tolerance Unidirectional Device
 CA = 5 % Tolerance Bidirectional Device
 AEC-Q101 Suffix
 Q = AEC-Q101 Compliant, 13-inch Reel
 QH = AEC-Q101 Compliant, 7-inch Reel

Environmental Specifications

Moisture Sensitivity Level 1
 ESD Classification (HBM)..... 3B

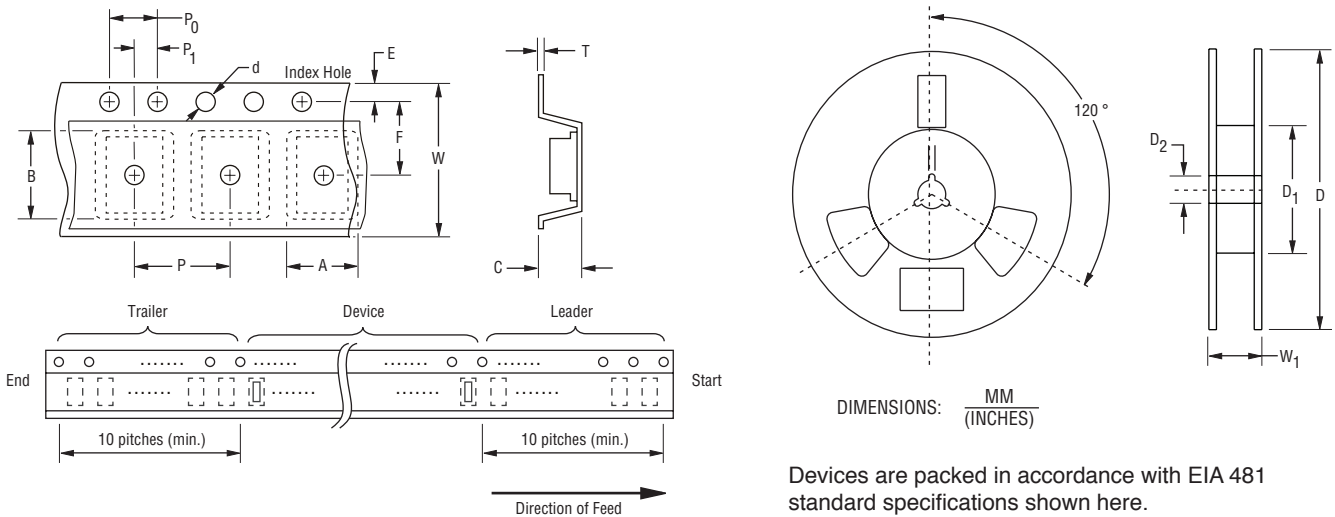
Specifications are subject to change without notice.
 The device characteristics and parameters in this data sheet can and do vary in different applications and actual device performance may vary over time.
 Users should verify actual device performance in their specific applications.

SMAJ-Q Transient Voltage Suppressor Diode Series

BOURNS®

Packaging Information

The product will be dispensed in tape and reel format (see diagram below).



Devices are packed in accordance with EIA 481 standard specifications shown here.

Item	Symbol	SMA (DO-214AC)	
		7-Inch Reel	13-Inch Reel
Carrier Width	A	$\frac{2.90 \pm 0.20}{(0.114 \pm 0.008)}$	
Carrier Length	B	$\frac{5.50 \pm 0.20}{(0.217 \pm 0.008)}$	
Carrier Depth	C	$\frac{2.26 \pm 0.20}{(0.089 \pm 0.008)}$	
Sprocket Hole	d	$\frac{1.50 \pm 0.10}{(0.061 \pm 0.004)}$	
Reel Outside Diameter	D	$\frac{178}{(7.008)}$	$\frac{330}{(12.992)}$
Reel Inner Diameter	D ₁	$\frac{50.0}{(1.969)}$ MIN.	
Feed Hole Diameter	D ₂	$\frac{13.0 \pm 0.20}{(0.512 \pm 0.008)}$	
Sprocket Hole Position	E	$\frac{1.75 \pm 0.10}{(0.069 \pm 0.004)}$	
Punch Hole Position	F	$\frac{5.50 \pm 0.05}{(0.217 \pm 0.002)}$	
Punch Hole Pitch	P	$\frac{4.00 \pm 0.10}{(0.157 \pm 0.004)}$	
Sprocket Hole Pitch	P ₀	$\frac{4.00 \pm 0.10}{(0.157 \pm 0.004)}$	
Embossment Center	P ₁	$\frac{2.00 \pm 0.05}{(0.079 \pm 0.002)}$	
Overall Tape Thickness	T	$\frac{0.30 \pm 0.10}{(0.012 \pm 0.004)}$	
Tape Width	W	$\frac{12.00 \pm 0.30}{(0.472 \pm 0.012)}$	
Reel Width	W ₁	$\frac{18.4}{(0.724)}$ MAX.	
Quantity per Reel	--	1,000	5,000

REV. 02/18

Specifications are subject to change without notice. The device characteristics and parameters in this data sheet can and do vary in different applications and actual device performance may vary over time. Users should verify actual device performance in their specific applications.